

PMBFJ108; PMBFJ109; PMBFJ110

N-channel junction FETs

Rev. 4 — 20 September 2011

Product data sheet

1. Product profile

1.1 General description

Symmetrical N-channel junction FETs in a SOT23 package.

1.2 Features and benefits

- High-speed switching
- Interchangeability of drain and source connections
- Low R_{DSon} at zero gate voltage (< 8 Ω for PMBFJ108).

1.3 Applications

- Analog switches
- Choppers and commutators
- Audio amplifiers.

2. Pinning information

Table 1. Pinning

Pin	Description[1]	Simplified outline Symbol
1	drain	□3
2	source	
3	gate	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

^[1] Drain and source are interchangeable.



3. Ordering information

Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
PMBFJ108	'-	plastic surface mounted package; 3 leads	SOT23		
PMBFJ109					
PMBFJ110	_				

4. Marking

Table 3. Marking

Type number	Marking code ^[1]
PMBFJ108	38*
PMBFJ109	39*
PMBFJ110	40*

^{[1] * =} p: Made in Hong Kong

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage (DC)		-	±25	V
V_{GSO}	gate-source voltage		-	-25	V
V_{GDO}	gate-drain voltage		-	-25	V
I _G	forward gate current (DC)		-	50	mA
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1] -	250	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-	150	°C

^[1] Mounted on an FR4 printed-circuit board.

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		<u>11</u> 500	K/W

^[1] Mounted on an FR4 printed-circuit board.

^{* =} t: Made in Malaysia

^{* =} W: Made in China

7. Static characteristics

Table 6. Static characteristics

 $T_i = 25 \, {}^{\circ}C.$

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{GSS}	gate-source leakage current	$V_{GS} = -15 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	-3	nA
I_{DSX}	drain-source cut-off current	$V_{GS} = -10 \text{ V}; V_{DS} = 5 \text{ V}$	-	-	3	nA
I_{DSS}	drain-source leakage current					
	PMBFJ108	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}$	80	-	-	mΑ
	PMBFJ109	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}$	40	-	-	mΑ
	PMBFJ110	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}$	10	-	-	mΑ
$V_{(BR)GSS}$	gate-source breakdown voltage	$I_G = -1 \mu A; V_{DS} = 0 V$	-	-	-25	V
V_{GSoff}	gate-source cut-off voltage					
	PMBFJ108	$I_D = 1 \mu A; V_{DS} = 5 V$	-10	-	-3	V
	PMBFJ109	$I_D = 1 \mu A; V_{DS} = 5 V$	-6	-	-2	V
	PMBFJ110	$I_D = 1 \mu A; V_{DS} = 5 V$	-4	-	-0.5	V
R_{DSon}	drain-source on-state resistance					
	PMBFJ108	$V_{GS} = 0 \text{ V}; V_{DS} = 0.1 \text{ V}$	-	-	8	Ω
	PMBFJ109	$V_{GS} = 0 \text{ V}; V_{DS} = 0.1 \text{ V}$	-	-	12	Ω
	PMBFJ110	$V_{GS} = 0 \text{ V}; V_{DS} = 0.1 \text{ V}$	-	-	18	Ω

8. Dynamic characteristics

Table 7. Dynamic characteristics

 $T_i = 25$ °C unless otherwise specified.

,							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
C _{iss}	input capacitance	$V_{DS} = 0 V; V_{GS} = -10 V; f = 1 MHz$		-	15	30	pF
		$V_{DS} = 0 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$		-	50	85	рF
C _{rss}	feedback capacitance	$V_{DS} = 0 \text{ V}; V_{GS} = -10 \text{ V}; f = 1 \text{ MHz}$		-	8	15	pF
Switching	g times (see <u>Figure 2</u>)						
t _d	delay time		<u>[1]</u>	-	2	-	ns
t _{on}	turn-on time		<u>[1]</u>	-	4	-	ns
ts	storage time		<u>[1]</u>	-	4	-	ns
t _{off}	turn-off time		<u>[1]</u>	-	6	-	ns

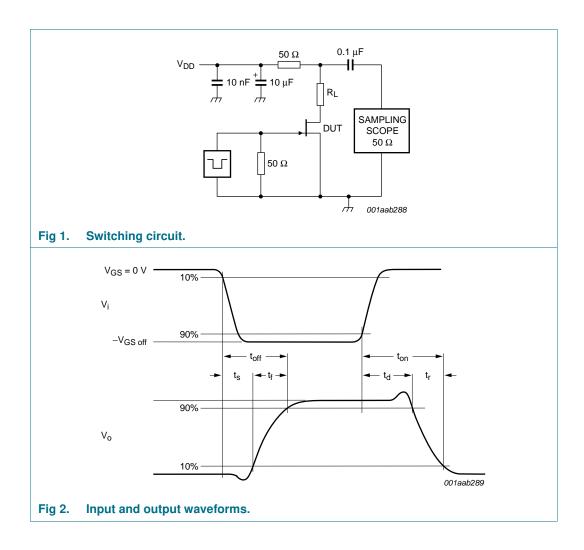
[1] Test conditions for switching times are as follows:

 V_{DD} = 1.5 V, V_{GS} = 0 V to V_{GSoff} (all types);

 $V_{GSoff} = -12 \text{ V}, R_L = 100 \Omega \text{ (PMBFJ108)};$

 $V_{GSoff} = -7 \text{ V}, R_L = 100 \Omega \text{ (PMBFJ109)};$

 V_{GSoff} = -5 V, R_L = 100 Ω (PMBFJ110).



Package outline

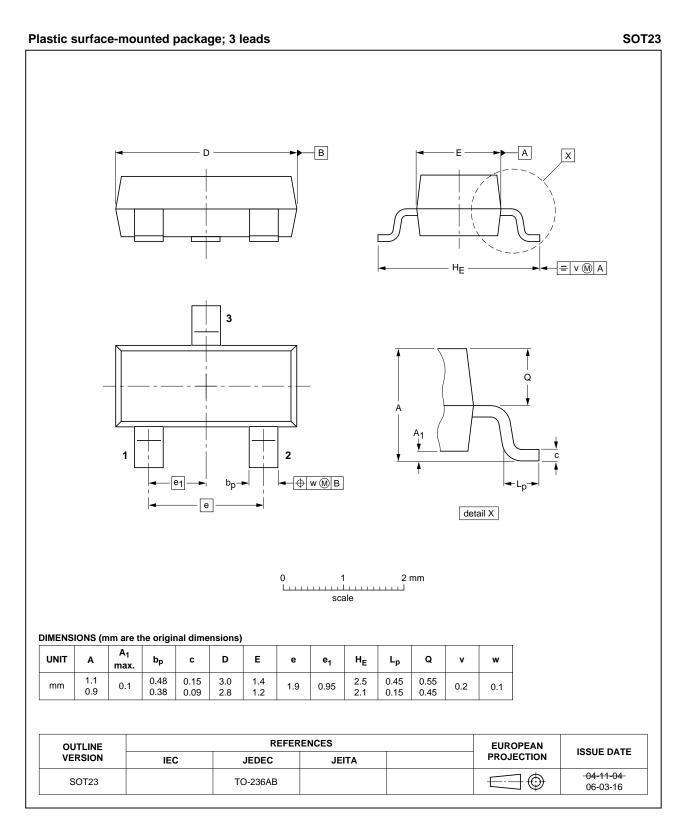


Fig 3. Package outline.

10. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMBFJ108_109_110 v.4	20110920	Product data sheet	-	PMBFJ108_109_110 v.3
Modifications:	guidelines o • Legal texts	of NXP Semiconductors.	ne new company n	comply with the new identity name where appropriate. atest version.
PMBFJ108_109_110 v.3 (9397 750 13401)	20040804	Product data sheet	-	PMBFJ108_109_110_CNV v.2
PMBFJ108_109_110_CNV v.2	19971201	Product specification	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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